## FAN5308

800mA High－Efficiency Step－Down DC－DC Converter

## Features

■ 96\％efficiency，synchronous operation
■ Adjustable output voltage options from 0.8 V to $\mathrm{V}_{\text {IN }}$
■ 2.5 V to 5.5 V input voltage range
■ Up to 800 mA output current
■ Fixed－frequency 1.3 MHz PWM operation
■ High－efficiency，power－save mode
■ 100\％duty cycle low－dropout operation
■ Soft－start
■ Output over－voltage protection
■ Dynamic output voltage positioning
－ $25 \mu \mathrm{~A}$ quiescent current
■ Thermal shutdown and short－circuit protection
－Pb－free $3 \times 3 \mathrm{~mm}$ 6－lead MLP package

## Applications

－Pocket PCs，PDAs
■ Cell phones
■ Battery－powered portable devices
■ Digital cameras
■ Hard disk drives
■ Set－top boxes
－Point－of－load power
■ Notebook computers
－Communications equipment

## Description

Designed for use in battery－powered applications，the FAN5308 is a high－efficiency，low－noise synchronous PWM current mode and pulse skip（power－save）mode DC－DC converter．It can provide up to 800 mA of output current over an input range from 2.5 V to 5.5 V ．The output voltage can be externally adjusted over a range of 0.8 V to 5.5 V by means of an external voltage divider．

At moderate and light loads，pulse skipping modulation is used．Dynamic voltage positioning is applied and the output voltage is shifted $0.8 \%$ above nominal value for increased headroom during load transients．At higher loads，the system automatically switches over to current mode PWM control，operating at 1.3 MHz ．A current mode control loop with fast transient response ensures excellent line and load regulation．To achieve high effi－ ciency and ensure long battery life，the quiescent current is reduced to $25 \mu \mathrm{~A}$ in power－save mode，and the supply current drops below $1 \mu \mathrm{~A}$ in shut－down mode．The FAN5308 is available in a 3x3mm 6－lead MLP package．

## Ordering Information

| Product Number | Output Voltage | Package Type | Order Code |
| :---: | :---: | :---: | :---: |
| FAN5308 | Adjustable | $3 \times 3 m m 6-$ Lead MLP | FAN5308MPX |

## Typical Application



Figure 1．Typical Application

## Pin Configuration



## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Parameter |  | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN }}$ |  | -0.3 | 7.0 | V |
| Voltage On Any Other Pin |  | -0.3 | $\mathrm{V}_{\mathrm{IN}}$ | V |
| Lead Soldering Temperature (10 seconds) |  |  | 260 | ${ }^{\circ} \mathrm{C}$ |
| Junction Temperature |  |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance, Junction-to-Case ( $\theta_{\text {JC }}$ ), 3x3mm 6-lead MLP ${ }^{(1)}$ |  |  | 8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Electrostatic Discharge Protection (ESD) Level ${ }^{(2)}$ | HBM | 4 |  | kV |
|  | CDM | 1 |  | kV |

## Notes:

1. Junction-to-ambient thermal resistance, $\theta_{\mathrm{JA}}$, is a strong function of PCB material, board thickness, thickness and number of copper planes, number of via used, diameter of via used, available copper surface, and attached heat sink characteristics.
2. Using Mil Std. 883E, method 3015.7 (Human Body Model) and EIA/JESD22C101-A (Charged Device Model).

## Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Parameter | Min. | Typ. | Max. | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Supply Voltage Range | 2.5 |  | 5.5 | V |
| Output Voltage Range, Adjustable Version | 0.8 |  | $\mathrm{~V}_{\text {IN }}$ | V |
| Output Current |  |  | 800 | mA |
| Inductor ${ }^{(3)}$ |  | 3.3 |  | $\mu \mathrm{H}$ |
| Input Capacitor ${ }^{(3)}$ |  | 10 |  | $\mu \mathrm{~F}$ |
| Output Capacitor ${ }^{(3)}$ |  | $2 \times 10$ |  | $\mu \mathrm{~F}$ |
| Operating Ambient Temperature Range | -40 |  | +85 | ${ }^{\circ} \mathrm{C}$ |
| Operating Junction Temperature Range | -40 |  | +125 | ${ }^{\circ} \mathrm{C}$ |

## Note:

3. Refer to the Applications section for details.

## Electrical Characteristics

$\mathrm{V}_{\text {IN }}=\mathrm{V}_{\text {OUT }}+0.6 \mathrm{~V}$ (minimum 2.5 V ) to 5.5 V , $\mathrm{I}_{\mathrm{OUT}}=350 \mathrm{~mA}, \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{EN}=\mathrm{V}_{\mathrm{IN}}, \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted. Typical values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions |  | Min. | Typ. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IN }}$ | Input Voltage | $0 \mathrm{~mA} \leq \mathrm{I}_{\text {OUT }} \leq 800 \mathrm{~mA}$ |  | 2.5 |  | 5.5 | V |
| $\mathrm{I}_{\mathrm{Q}}$ | Quiescent Current | $\mathrm{I}_{\text {Out }}=0 \mathrm{~mA}$, Device is not switching |  |  | 20 | 35 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{I}_{\mathrm{OUT}}=0 \mathrm{~mA}$, Device is switching ${ }^{(4)}$ | $\mathrm{R} 2=10 \mathrm{k} \Omega$ |  | 50 |  | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{R} 2=100 \mathrm{k} \Omega$ |  | 25 |  | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {SD }}$ | Shutdown Supply Current | EN = GND |  |  | 0.1 | 1.0 | $\mu \mathrm{A}$ |
| $\mathrm{V}_{\text {UVLO }}$ | Under-Voltage Lockout Threshold | $\mathrm{V}_{\text {IN }}$ Rising |  | 1.9 | 2.1 | 2.3 | V |
|  |  | Hysteresis |  |  | 150 |  | mV |
| $\mathrm{V}_{\text {ENH }}$ | Enable High Input Voltage |  |  | 1.3 |  |  | V |
| $\mathrm{V}_{\mathrm{ENL}}$ | Enable Low Input Voltage |  |  |  |  | 0.4 | V |
| $\mathrm{I}_{\text {EN }}$ | EN Input Bias Current | $\mathrm{EN}=\mathrm{V}_{\text {IN }}$ or GND |  |  | 0.01 | 0.10 | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\text {DS-ON }}$ | PMOS On Resistance | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{GS}}=5.5 \mathrm{~V}$ |  |  | 250 | 350 |  |
|  |  | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{GS}}=2.5 \mathrm{~V}$ |  |  | 300 | 400 | $\Omega$ |
|  | NMOS On Resistance | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{GS}}=5.5 \mathrm{~V}$ |  |  | 200 | 300 |  |
|  |  | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{GS}}=2.5 \mathrm{~V}$ |  |  | 250 | 350 |  |
| $\mathrm{I}_{\text {LIM }}$ | P-channel Current Limit | $2.5 \mathrm{~V}<\mathrm{V}_{\text {IN }}<5.5 \mathrm{~V}$ |  | 1300 | 1500 | 2000 | mA |
| $\mathrm{f}_{\text {OSC }}$ | Oscillator Frequency |  |  | 1000 | 1300 | 1500 | KHz |
| $\mathrm{I}_{\mathrm{lkg}}^{\text {_ }}$ (N) | N-Channel Leakage Current | $\mathrm{V}_{\mathrm{DS}}=5.5 \mathrm{~V}$ |  |  | 0.1 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{lkg}}^{\text {_ }}$ (P) | P-Channel Leakage Current | $\mathrm{V}_{\mathrm{DS}}=5.5 \mathrm{~V}$ |  |  | 0.1 | 1 | $\mu \mathrm{A}$ |
|  | Line Regulation | $\mathrm{l}_{\text {OUT }}=10 \mathrm{~mA}$ |  |  | 0.16 |  | \%/V |
|  | Load Regulation | $350 \mathrm{~mA} \leq \mathrm{I}_{\text {OUT }} \leq 800 \mathrm{~mA}$ |  |  | 0.15 |  | \% |
| $\mathrm{V}_{\text {REF }}$ | Reference Voltage |  |  |  | 0.8 |  | V |
|  | Output DC Voltage Accuracy ${ }^{(5)}$ | $0 \mathrm{~mA} \leq \mathrm{I}_{\text {OUT }} \leq 800 \mathrm{~mA}$ |  | -3 |  | +3 | \% |
|  | Over-Temperature Protection | PWM Mode Only $350 \mathrm{~mA} \leq \mathrm{I}_{\text {OUT }} \leq$ 800mA | Rising Temperature |  | 150 |  | ${ }^{\circ} \mathrm{C}$ |
|  |  |  | Hysteresis |  | 20 |  | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\text {ST }}$ | Start-Up Time | $\mathrm{I}_{\text {OUT }}=800 \mathrm{~mA}, \mathrm{C}_{\text {OUT }}=20 \mu \mathrm{~F}$ |  |  | 800 |  | $\mu \mathrm{s}$ |

## Notes:

4. Refer to the Application section for details.
5. For output voltages $\leq 1.2 \mathrm{~V}, \mathrm{a} 40 \mu \mathrm{~F}$ output capacitor value is required to achieve a maximum output accuracy of $3 \%$ while operating in power-save mode (PFM mode).

## Typical Performance Characteristics

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\mathrm{IN}}=10 \mu \mathrm{~F}, \mathrm{C}_{\text {OUT }}=20 \mu \mathrm{~F}, \mathrm{~L}=3.3 \mu \mathrm{H}, \mathrm{R}_{2}=10 \mathrm{k} \Omega$, unless otherwise noted.


Figure 3. Efficiency vs. Load Current


Figure 5. Efficiency vs. Load Current


Figure 7. Quiescent Current vs. Input Voltage


Figure 4. Efficiency vs. Load Current


Figure 6. Output Voltage vs. Load Current


Figure 8. Frequency vs. Temperature

Typical Performance Characteristics (Continued)
$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{C}_{\text {IN }}=10 \mu \mathrm{~F}, \mathrm{C}_{\text {OUT }}=20 \mu \mathrm{~F}, \mathrm{~L}=3.3 \mu \mathrm{H}, \mathrm{R}_{2}=10 \mathrm{k} \Omega$, unless otherwise noted.


Figure 9. PWM Mode


Figure 11. Load Transient Response


Figure 13. Start-Up Response


Figure 10. Power-Save Mode


Figure 12. Load Transient Response


Figure 14. Start-Up Response

## Block Diagram



Figure 15. Block Diagram

## Detailed Operation Description

The FAN5308 is a step-down converter operating in a current-mode PFM/PWM architecture with a typical switching frequency of 1.3 MHz . At moderate to heavy loads, the converter operates in pulse-width-modulation (PWM) mode. At light loads, the converter enters a power-save mode (PFM pulse skipping) to keep the efficiency high.

## PWM Mode

In PWM mode, the device operates at a fixed frequency of 1.3 MHz . At the beginning of each clock cycle, the P channel transistor is turned on. The inductor current ramps up and is monitored via an internal circuit. The P channel switch is turned off when the sensed current causes the PWM comparator to trip when the output voltage is in regulation or when the inductor current reaches the current limit (set internally to typically 1500 mA ). After a minimum dead time, the N -channel transistor is turned on and the inductor current ramps down. As the clock cycle is completed, the N-channel switch is turned off and the next clock cycle starts.

## PFM (Power-Save) Mode

As the load current decreases and the inductor current reaches negative value, the converter enters pulse-fre-quency-modulation (PFM) mode. The transition point for the PFM mode is given by the equation:
$\mathrm{I}_{\text {OUT }}=\mathrm{V}_{\text {OUT }} \times \frac{1-\left(\mathrm{V}_{\text {OUT }} / \mathrm{V}_{\text {IN }}\right)}{2 \times \mathrm{L} \times \mathrm{f}}$
EQ. 1

The typical output current, when the device enters PFM mode, is 150 mA for input voltage of 3.6 V and output voltage of 1.2 V . In PFM mode, the device operates with a variable frequency and constant peak current, thus reducing the quiescent current to minimum. Consequently, the high efficiency is maintained at light loads. As soon as the output voltage falls below a threshold, set at $0.8 \%$ above the nominal value, the P-channel transistor is turned on and the inductor current ramps up. The P-channel switch turns off and the N -channel turns on as the peak inductor current is reached (typical 450 mA ).

The N -channel transistor is turned off before the inductor current becomes negative. At this time, the P-channel is switched on again, starting the next pulse. The converter continues these pulses until the high threshold (typical $1.6 \%$ above nominal value) is reached. A higher output voltage in PFM mode gives additional headroom for the voltage drop during a load transient from light to full load. The voltage overshoot during this load transient is also minimized due to active regulation during turn on of the N -channel rectifier switch. The device stays in sleep mode until the output voltage falls below the low threshold. The FAN5308 enters the PWM mode as soon as the output voltage can no longer be regulated in PFM with constant peak current.

## 100\% Duty Cycle Operation

As the input voltage approaches the output voltage and the duty cycle exceeds the typical $95 \%$, the converter turns the P-channel transistor continuously on. In this mode, the output voltage is equal to the input voltage, minus the voltage drop across the P -channel transistor:
$\mathrm{V}_{\text {OUT }}=\mathrm{V}_{\text {IN }}-\mathrm{I}_{\text {LOAD }} \times\left(\mathrm{R}_{\mathrm{dsON}}+\mathrm{R}_{\mathrm{L}}\right)$
where:
$\mathrm{R}_{\mathrm{dsON}}=\mathrm{P}$-channel switch on resistance
$\mathrm{l}_{\text {LOAD }}=$ Output current
$R_{L}=$ Inductor DC resistance

## UVLO and Soft Start

The reference and the circuit remain reset until the $\mathrm{V}_{\mathrm{IN}}$ crosses its UVLO threshold.

The FAN5308 has an internal soft-start circuit that limits the inrush current during start-up. This prevents possible voltage drops of the input voltage and eliminates the output voltage overshoot. The soft-start is implemented as a digital circuit, increasing the switch current in four steps to the P-channel current limit ( 1500 mA ). Typical start-up time for a $20 \mu \mathrm{~F}$ output capacitor and a load current of 800 mA is $800 \mu \mathrm{~s}$.

## Short-Circuit Protection

The switch peak current is limited cycle-by-cycle to a typical value of 1500 mA . In the event of an output voltage short circuit, the device operates with a frequency of 400 kHz and minimum duty cycle; therefore, the average input current is typically 200 mA .

## Thermal Shutdown

When the die temperature exceeds $150^{\circ} \mathrm{C}$, a reset occurs and remains in effect until the die cools to $130^{\circ} \mathrm{C}$. At that time, the circuit is allowed to restart.

## Applications Information

## Setting the Output Voltage

The internal reference is 0.8 V (typical). The output voltage is divided by a resistor divider, R1 and R2 to the FB pin. The output voltage is given by:

$$
\begin{equation*}
\mathrm{V}_{\mathrm{OUT}}=\mathrm{V}_{\mathrm{REF}} \times\left(1+\left(\frac{\mathrm{R} 1}{\mathrm{R} 2}\right)\right) \tag{EQ. 3}
\end{equation*}
$$

where $R_{1}+R_{2}<800 K \Omega$.
According to this equation, and assuming desired output voltage of 1.5096 V , and given $\mathrm{R} 2=10 \mathrm{k} \Omega$, the calculated value of $R 1$ is $8.87 \mathrm{k} \Omega$. If quiescent current is a key design parameter, a higher value feedback resistor can be used (e.g. R2 $=100 \mathrm{k} \Omega$ ) and a small bypass capacitor of 10 pF is required in parallel with the upper resistor, as shown in Figure 16.


Figure 16. Setting the Output Voltage

## Inductor Selection

The inductor parameters directly related to the device's performances are saturation current and DC resistance. The FAN5308 operates with a typical inductor value of $3.3 \mu \mathrm{H}$. The lower the DC resistance, the higher the efficiency. For saturation current, the inductor should be rated higher than the maximum load current plus half of the inductor ripple current.

This is calculated as follows:

$$
\begin{equation*}
\Delta \mathrm{I}_{\mathrm{L}}=\mathrm{V}_{\mathrm{OUT}} \times \frac{1-\left(\mathrm{V}_{\mathrm{OUT}} / \mathrm{V}_{\mathrm{IN}}\right)}{\mathrm{L} \times f} \tag{EQ. 4}
\end{equation*}
$$

where:
$\Delta \mathrm{I}_{\mathrm{L}}=$ Inductor Ripple Current
$f=$ Switching Frequency
L = Inductor Value

| Inductor Value | Vendor | Part Number |
| :---: | :---: | :---: |
| $3.3 \mu \mathrm{H}$ | Panasonic | ELL6PM3R3N |
| $3.3 \mu \mathrm{H}$ | Murata | LQS66C3R3M04 |

Table 1: Recommended Inductors

## Capacitors Selection

For best performances, a low-ESR input capacitor is required. A ceramic capacitor of at least $10 \mu \mathrm{~F}$, placed close to the $\mathrm{V}_{\mathbb{I N}}$ and AGND pins, is recommended. The output capacitor determines the output ripple and the transient response.

| Capacitor <br> Value | Vendor | Part Number |
| :---: | :---: | :---: |
| 10رF | Taiyo <br> Yuden | JMK212BJ106MG |
|  | TDK | JMK316BJ106KL |
|  | C2012X5ROJ106K |  |
|  | C3216X5ROJ106M |  |
|  | Murata | GRM32ER61C106K |

Table 2: Recommended Capacitors

## PCB Layout Recommendations

The recommended PCB layout is shown in Figure 17. The inherently high peak currents and switching frequency of power supplies require careful PCB layout design.


Figure 17. Recommended PCB Layout
Use wide traces for high-current paths and place the input capacitor, the inductor, and the output capacitor as close as possible to the integrated circuit terminals. To minimize voltage stress to the device resulting from everpresent switching spikes, use an input bypass capacitor with low ESR. Note that the peak amplitude of the switching spikes depends upon the load current; the higher the load current, the higher the switching spikes. The resistor divider that sets the output voltage should be routed away from the inductor to avoid RF coupling. The ground plane at the bottom side of the PCB acts as an electromagnetic shield to reduce EMI.
For more board layout recommendations, download the Fairchild application note PCB Grounding System and FAN2001/FAN2011 High-Performance DC-DC Converters (AN-42036).

## Mechanical Dimensions

Dimensions are in millimeters unless otherwise noted.


RECOMMENDED LAND PATTERN

Figure 18. 3x3mm 6-Lead MLP

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| FRFET ${ }^{\text {® }}$ - | PDP-SPM ${ }^{\text {TM }}$ | SuperFET ${ }^{\text {TM }}$ | $U H C^{\varnothing}$ |
| Global Power Resource ${ }^{\text {sul }}$ | Power $220{ }^{\circ}$ | SuperSOTM-3 | UniFET ${ }^{\text {TM }}$ |
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